Sign-reversal of drag in bilayer systems with in-plane periodic potential modulation

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We develop a theory for describing frictional drag in bilayer systems with in-plane periodic potential modulations, and use it to investigate the drag between bilayer systems in which one of the layers is modulated in one direction. At low temperatures, as the density of carriers in the modulated layer is changed, we show that the transresistivity component in the direction of modulation can change its sign. We also give a physical explanation for this behavior.

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Throughout past decade there has been a great deal of experimental and theoretical activity in frictional drag in bilayer systems, following the sem in alexperiments by Gram ila et al. These drag experim ents involve a double quantum well system where the layers are individually contacted by ingenious fabrication techniques. The barrier between the wells is made thick enough to suppress tunneling but thin enough to allow signi cant interlayer interactions. An average current density j is driven through layer 1 and circuit is kept open in layer 2, so that  $\frac{1}{12} = 0$ . The interlayer interaction causes the electrons in layer 1 to drag along the electrons in layer 2, and hence a counterbalancing electric eld E 2 form s in layer 2 to maintain a zero net 1/2. The transresistivity tensor  $^{\$}$  21, de ned by E 2 =  $^{\$}$  21 j<sub>1</sub>, can be extracted experim entally and can reveal in portant inform ation about the properties of the e ective interlayer interactions, the individual layers and the coupled bilayer system.

Since Gram ila et al.'s original work<sup>1</sup>, which was done on a closely spaced electron (electron system at low tem peratures without an applied magnetic eld, many variations on the them e of the original experim ents have been performed. For instance, drag has been measured in electron {hole<sup>2</sup> and hole {hole<sup>3</sup> systems, in widely separated layers<sup>4;5</sup>, and in the presence of a perpendicular magnetic eld. 3;6{8 Very recently, low {density systems have been studied to probe the suggested m etal insulator phase transition in strongly correlated disordered twodim ensional system s.9;10 Another modern trend is to exam ine m esoscopic e ects in Coulomb drag. $^{11}{13}$ . In general, drag without an applied B - eld is reasonably well understood within the framework of a standard weak-interlayer coupling theory. 14 {16 The theory successfully accounts for several unusual features such as large enhancem ents in the transresistivity (up to an order the magnitude; some intriguing discrepancies however do persist for the most dilute systems studied<sup>10</sup>) due to intralayer correlations<sup>17</sup> and plasm on mediated scattering. 18;19 On the other hand, the understanding of magnetodrag (i.e., drag in the presence of a perpendicular B - eld) in bilayer systems is less complete, and several puzzling experim ental results remain unexplained.

For instance, under certain circum stances, the diagonal terms in the magnetotransresistivity (  $_{21}^{\rm xx}$  and  $_{21}^{\rm yy}$ ) has been observed to reverse sign when the chemical potential is changed in one layer while being kept xed in the other. This sign reversal with changing chemical potential (which incidentally has not been observed at B = 0) cannot be obtained from magnetodrag calculations using the self-consistent Born approximation,  $^{21;22}$  and despite recent theoretical progress,  $^{23}$  a fully satisfactory explanation of this phenomenon is not yet available.

In this paper, we suggest that a reversal of the sign of the transresistivity is possible at B = 0 in bilayer systems that have periodic potential modulations in the plane of the layers. The periodic potential modulation creates m in i-bands, and the charge carriers can evolve from electron-like to hole-like behavior with a relatively sm all change in the density. Furtherm ore, for system s that are modulated in one direction, it is possible to observe \skewed drag" (i.e., non-zero o -diagonal elem ents of 21), implying that the electric eld response in the drag layer is in a di erent direction from that of the driving current. This dem on strates the important role bandstructure plays in determ ining the transresistivity of the system . 24 W e note that experim ents on two-dim ensional electron gases with strong potential modulations in one direction have already been reported in the literature<sup>25</sup>, and hence we believe that the theory described below is am enable to experim ental tests in near future.

To investigate drag in these m odulated system s, we use the K ubo form alism  $^{15;16}$  to calculate the transconductivity tensor  $^\$$   $_{21}$ , which is related to the transresistivity by  $^\$$   $_{21}$  =  $^\$$   $_{22}^\$$   $_{21}^\$$   $_{11}$  in the weak interlayer coupling lim it. In this method, the transconductivity is expressed as a current-current correlation function, which can be calculated with standard perturbation theory techniques.

The H am iltonian of the system is  $\hat{H} = \prod_{i=1,2} \hat{H_i} + \hat{H_{12}}$ ; where  $\hat{H_i}$  is the H am iltonian of layer i and  $\hat{H_{12}}$  is the interlayer interaction term. We assume  $\hat{H_{21}}$  is due to C oulomb interactions, so that  $\hat{H_{12}} = A^{-1}$   $\hat{n_1}(q)\hat{n_2}(q)V_{12}(q)$ ; where  $\hat{n_i}(q)$  and  $V_{12}(q)$  are the Fourier transforms of the density operator and the interlayer C oulomb interaction, respectively.

W e de ne, within the M atsubara form alism ,  $^{\sim}$  to be the correlation function  $^{26}$ 

For systems that have a periodic potential modulation with reciprocalvectors G , only q  $\,{\rm q^0}={\rm G}\,$  terms are non-zero. Expanding in powers of  $V_{12}$ , the rst non-vanishing term for  $_{21}$  in the dc limit is the second order term. We obtain

$$\frac{e^{2}}{hA} \times X \times V_{12}(q)V_{12}(q+G_{1})_{G_{1}G_{2}}$$

$$\frac{Z_{1}}{2} \frac{d!}{2} \cdot (q;q+G_{2};!+i0^{+};!-i0^{+})$$

$$\frac{q}{2} \cdot (q;q+G_{1};!+i0^{+};!-i0^{+})[\theta_{!} \cdot n_{B}(!)]$$

$$(2)$$

Evaluation of  $(q;q+G;!+i0^+;!-i0^+)$  is analogous to Ref. 16. In this paper, we assume the system is in the weak scattering limit, allowing us to ignore vertex corrections at the charge vertices. Then, one obtains

$$\begin{array}{l}
\sim (q;q+G;!+i0^{+};!-i0^{+}) \\
= \frac{4}{A} \sum_{knn^{0}} [v_{n^{0}k+q} t_{r;n^{0}} (k+q) v_{nk} t_{r;n} (k)] \\
[(n_{F} ("_{nk}) n_{F} ("_{nk} !)] ("_{nk} "_{n^{0}k+q} !) \\
(k+qn^{0};kn;q) (kn;k+qn^{0}; q G):
\end{array}$$
(3)

Here,  $v_{nk}$  is the band velocity, " is the energy,  $n_F$  (") =  $[\exp((" )) + 1]^{-1}$  ( is the chem ical potential),  $_{tr}$  is the transport time,  $(k^0n^0;kn;q) = hk^0n^0j\exp(iqr) kni (n;n^0)$  are the band indices)]. The  $^{\$}_{21}$  obtained using Eq. (2) and the weak scattering result, Eq. (3), can also be derived from the sem iclassical Boltzmann equation.  $^{19}$ 

A complete calculation of drag, using (3) in (2), is an arduous task, requiring a numerical evaluation of the band-structure(s) of the layers, calculation of the matrix elements ( $k^0n^0;kn;q$ ), and summation of dierent bands n, and reciprocal lattice vectors G . For incommensurate lattices one always has  $G_1=0=G_2$ , and in the remaining part of the paper we assume this to be the case. The other technical steps do not pose conceptual diculties, and in the present context we not it appropriate to consider simplied systems where to a certain extent analytic progress can be made, and for which the physics is transparent.

The central issue of this paper is the sign reversal of the drag. We demonstrate this rst for a 1{dimensional model, neglecting interband processes and the momentum dependence of the transport relaxation time. For this case, the correlation function (3) becomes =  $_{\rm tr}F$  (q;!), where

$$F (q;!) = \frac{2}{L} X (v_k v_{k+q})$$

$$= X [n_F ("_k) n_F ("_{k+q})] ("_k "_{k+q} !)$$

$$= X sign (v_{k_i} v_{k_i+q}) [n_F ("_{k_i}) n_F ("_{k_i+q})]; (4)$$

where  $k_i$  are the solutions of  $\mathbf{l}_{k_i}$   $\mathbf{l}_{k_i+q}$  ! = 0. For illustrative purposes, we consider a cosine-band,  $\mathbf{l}_k = h^2 = (m \ a^2) \cos ka$ , for which there are two (or none) solutions, and one nds

F (q;!) = sign (
$$v_2$$
  $v_1$ ) [ $n_F$  (  $"_2$ )  $n_F$  ( $"_1$ )
$$n_F$$
 (  $"_1$ )  $n_F$  ( $"_2$ )]: (5)

At half{ lling the chem ical potential vanishes, and making use of  $n_F;=0$  ( ") = 1  $n_F;=0$  ("), it is easy to see that the result (5) vanishes identically. Thus, in an experiment where one of the subsystems is kept unchanged while in the other the chem ical potential is moved through half{ lling, the drag will change sign. While the above discussion is an important demonstration of principle, it is necessary to also consider periodically modulated two-dimensional electron gases, which are the most commonly studied systems in this context.  $^{27}$ 

A system which has an identical periodic modulation in both x{ and y{directions is characterized by particle { hole sym metry, and it seems natural that the drag passes through zero when the two carrier species are matched. The experimentally most relevant systems are those, however, where the modulation is only in one direction<sup>25;28</sup> (the strongest modulations have been achieved for these systems) and hence we choose the model system as follows: (1) There is a single band (the dispersion law and corresponding density of states are illustrated in Fig. 1) with a tight-binding dispersion relation " $(k_x; k_y) = h^2 [1 \cos(k_x a)] = (m_x a^2) +$  $h^2 k_v^2 = (2m_v)$ ; and hence the velocity components are  $v_x(k_x) = h \sin(k_x a) = (m_x a)$  and  $v_y(k_y) = hk_y = m_y$ : (2) tr is k-independent. (3) The interlayer interaction  $V_{12}$  (q) is signi cant only for smallq.29

At low temperatures, it would appear permissible to expand in !, because  $@n_B\ (!)=@!$  in the integrand cuts of the higher! contributions. Following this procedure yields an analytic expression for F . and the resulting drag resistivity obeys the familiar T  $^2$  {dependence known from unmodulated two {dimensional system s  $^1;1^4$ . In this scheme, the transresisitivity diverges when =  $2h^2=(m_{\times}a^2)$  with the opposite sign from the low density  $^{\rm xx}$ . This divergence, which is related to the divergence in the density of states at this energy (see Fig. 1), is unphysical because it only occurs in the experimentally unreachable T = 0 limit. Nevertheless, it is interesting to observe that this approximation leads to a change of sign in the transconductance, and we should expect this behavior to be most prominent when =  $2h^2=(m_{\times}a^2)$ .

To cure this spurious divergence one must avoid expansions, and perform a numerical evaluation. As a starting point we have found it convenient to use

$$F^{x}(q;!) = \frac{m_{y}}{(2)^{2} h q_{y} m_{x} a} = aZ_{q_{x}=2} dk_{x}$$

$$= a + q_{x}=2$$

$$[\sin (k_{x} q_{x}=2) a \sin (k_{x} + q_{x}=2) a]$$

$$[h_{F}(k_{x} q_{x}=2; k_{y0}(k_{x}) q_{y}=2)$$

$$n_{F}(k_{x} + q_{x}=2; k_{y0}(k_{x}) + q_{y}=2)]; (6)$$

w here

$$k_{y0} (k_x) = \frac{m_y}{h^2 q_y} h! + \frac{h^2}{m_x a^2} (\cos (k_x + q_x = 2) a)$$

$$\cos (k_x - q_x = 2) a) : (7)$$

W hile the K ubo form ula gives the transconductivity, it is often m ost convenient to express the results in terms of transresissistivity (this is the object usually recorded in experiments)  $^{\$}$   $_{21}$ , whose components are given by

$$\frac{xx}{21} = \frac{\frac{xx}{21}}{\frac{xx}{xx} \frac{xx}{xx} \frac{xx}{xx} \frac{xx}{xx}}, \frac{\frac{xx}{21}}{\frac{xx}{xx} \frac{xx}{xx}};$$
 (8)

and analogously for the yy-com ponent. The transresisivity tensor has the additional advantage that is does not involve the transport relaxation times for the individual layers, as long as these are momentum independent. The computed transresisitivity is shown in Fig. 2 for four different temperatures. The most important feature is that the drag indeed changes sign; the eect is most prominent for low temperatures, and densities close to a fully-occupied band. In Figs. 3 and 4 we compare the xx-and yy-components of the computed transconductances (the xx-component was used in calculating the results of Fig. 2). We observe that the sign change does not take place for  $\frac{yy}{12}$ , nevertheless an interesting double-peak structure emerges.

An analysis of the several assum ptions made in our calculations is now in place. We have assumed that the system only has one band. Clearly, this assumption breaks down when the density so large that Ferm i energy signi cantly exceeds  $2h^2 = (2m_x a^2)$ , because the carriers will start to occupy higher bands. We also have assumed that tem perature is low enough that the inelastic mean free path 'in is much longer than period of the potential modulation, a. For nite 'in the system is roughly divided into coherent regions of order  $\frac{2}{in}$  . If  $\frac{1}{in} < a$ , the electrons do not coherently feel the periodic potential, and the drag characteristics will be given by an average of the drag over the density uctuation caused by the potential modulation. Since the system as a whole acts like a (nearly) uniform system in this case, e ects described in this paper will not be observable at tem peratures for which 'in < a.

To sum m arize, we have developed a theory for drag in bilayer systems where there is a periodic potential modulation. We have calculated the drag for the case where there is potential modulation in one direction in one of the two layers. We not that at low temperatures the transresistivity changes sign as the density is increased. The anisotropy of the transresistivity tensor in plies that one should be able to see Hall drag. Experimentally, it may be possible to fabricate the system investigated here by by overgrowing a pair of quantum wells over a cleaved edge, or using lithographic techniques. 30

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- Note that this de nition is dierent from the used in Ref. 16. The de ned in Ref. 16 is appropriate only for hom ogenous systems.
- <sup>27</sup> Im portantly, signi cant progress towards fabricating modulated 1{dim ensional nanow ires has recently been achieved by M.S.Gudiksen, L.J.Lauhon, J.W ang, D.C.Sm ith, and C.M.Lieber, Nature, 415, 617 (2002).
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- In our calculations we use the statically screened C oulom b interaction, V (q) =  $(2 e^2 = )q = [2q_{TF,1}q_{TF,2} \sinh qd + q(q + q_{TF,1} + q_{TF,2}) \exp qd]$ , where  $q_{TF,i}$  are the Thom as-Ferm i screening wave-numbers for the two layers. For the modulated layer the screening wave-number has a slight temperature and density dependence, which, however, has a rather smalle ect for the calculated drag.
- $^{\rm 30}$  T .J.G ram ila, private com m unication.

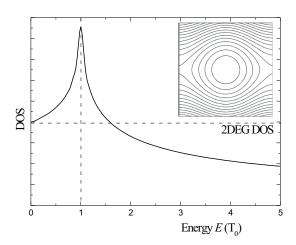


FIG.1. The density of states for a two-dim ensional system with periodical modulation in one direction. The inset shows the constant energy surfaces for the dispersion relation used in this work. The energy is in units of  $k_B \ T_0 = \ 2h^2 = (m \ _x \ _a^2)$ .

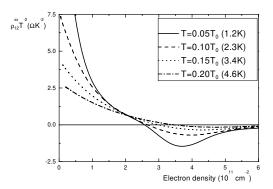


FIG. 2. The calculated transresistivity  $_{\rm n}^{\rm rx}$ , as a function of the density for four di event temperatures.

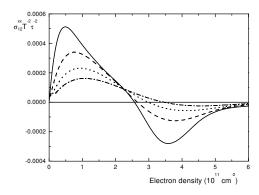


FIG . 3. The norm alized transconductivity  $_0^{xx}$ , as a function of the density for the sam e tem peratures as in Fig. 1.

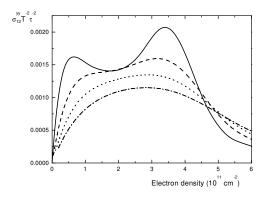


FIG .4. The normalized transconductivity  $_{D}^{YY}$ , as a function of the density for four di erent temperatures.